



# Electrodeposition of Hole-Transport Layer on Methylammonium Lead Iodide Film: A Strategy To Assemble Perovskite Solar Cells

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S Supporting Information

he emergence of organic-inorganic metal halide perov-L skites as active components in solar cells has sparked a great interest in the scientific community. A steep rise was witnessed in the power conversion efficiencies, which currently peaks at a certified value of 22.7%.<sup>1</sup> The attractiveness of these materials resides in their exceptional defect tolerance,<sup>2,3</sup> tunable light absorption and emission properties,<sup>4,5</sup> enhanced charge carrier transport and lifetime,<sup>4</sup> and cost-effective preparation and processability.<sup>6</sup> Applications beyond solar cells have also been studied, in light emitting diodes,<sup>7,8</sup> lasers,<sup>8</sup> photodetectors,<sup>9,10</sup> X-ray detectors,<sup>11</sup>  $\gamma$ -detectors,<sup>12</sup> and smart windows.<sup>13</sup>

Several research groups have focused on the synthesis of new organic hole-transporting materials (HTMs) for perovskite solar cells (PSCs).<sup>14-16</sup> An emerging class of HTMs is the family of organic polymers, which inherently possesses higher hole mobility than dopant-free small molecules.<sup>16</sup> Interestingly, this growing interest has not been accompanied by the growth in the arsenal of deposition techniques. To date, spin-coating remains the preferred choice to deposit such hole conducting polymer films.

In a n-i-p PSC design, hole conducting layers, mainly consisting of polymeric materials (e.g., P3HT<sup>17-19</sup> and PTAA<sup>19</sup>) that are soluble in perovskite antisolvents are studied. Although it was demonstrated that PEDOT accepts holes as effectively as spiro-OMeTAD,<sup>20</sup> its use apart from a few examples,<sup>21-23</sup> has been restricted to inverted SC designs (p-i-n junction). The direct spin-coating of the aqueous PEDOT: PSS solution is not a good option because it is known to degrade the perovskite layer. The inverted designs, however, pose further challenges such as overcoming the energy mismatch between FTO/PEDOT and attaining adequate surface coverage of the perovskite layer, which is determined by the morphology of the underlying PEDOT.

Although electrochemical deposition of the HTM layer has shown promising results in the case of dye-sensitized solar cells,<sup>24</sup> it remained an elusive task for the n-i-p PSC architecture up to this point. This is mainly because of the instability of MAPbI3 in polar solvents,<sup>25</sup> in which most electrochemical syntheses are carried out. Further complications arise from the dynamic exchange between the cations and halide ions in the perovskite layer and those present in the electrolyte. Such an exchange of ions can significantly alter the composition of the perovskite layer.<sup>26</sup> It has been demonstrated recently that the electrochemical properties of MAPbI<sub>3</sub><sup>27-29</sup> and related materials<sup>30-34</sup> can be studied in dichloromethane based electrolytes. Special care must be exercised while conducting electrodeposition, because an external electrochemical bias can induce unintended side reactions (e.g., corrosion of the perovskite layer).<sup>29</sup> However, by implementing carefully controlled conditions, one can employ electrodeposition as a technique and utilize its superior control over several efficiency-determining factors (e.g., morphology, regularity, conductivity, optical absorption, and layer thickness).

In this study, we report the electrochemical deposition of PEDOT (HTM layer) directly on the MAPbI<sub>3</sub> film deposited on a  $FTO/TiO_2$  electrode and its implementation in a perovskite solar cell (PSC) with an n-i-p architecture (Scheme 1). The effect of electrochemical post-treatments of the HTM layer on the performance of PSC has also been scrutinized.

#### RESULTS AND DISCUSSION

Electropolymerization of Hole-Transport Layer. The first step was to ensure that the MAPbI<sub>3</sub> layer remains intact during the electropolymerization. FTO/TiO<sub>2</sub>/MAPbI<sub>3</sub> electro-

Scheme 1. Illustration of the Assembly and Operation of the Perovskite Solar Cell with PEDOT Hole-Transporter



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**Figure 1.** (A) Potentiodynamic deposition of PEDOT with 25 mV s<sup>-1</sup> sweep rate in a 0.01 M bis-EDOT, 0.1 M Bu<sub>4</sub>NPF<sub>6</sub> DCM on a PSC architecture (FTO/bl-TiO<sub>2</sub>/mp-TiO<sub>2</sub>/MAPbI<sub>3</sub>) employing a thin MAPbI<sub>3</sub> layer. (B) UV–vis absorbance spectra recorded after each cycle at E = 0.0 V during polymerization. (C) First half-cycle of the potentiodynamic deposition plotted together with the absorbance change at 700 nm. (D) Potentiostatic deposition of PEDOT at different potentials in a 0.01 M bis-EDOT, 0.1 M Bu<sub>4</sub>NPF<sub>6</sub> DCM solution on a PSC architecture employing regular thickness MAPbI<sub>3</sub> layers with a polymerization charge density of 10 mC cm<sup>-2</sup>. (E) UV–vis absorbance spectra of PSCs after PEDOT electrodeposition at E = 0.9 V for different polymerization charge densities. (F) Absorbance change of the PSCs compared to a HTM-free cell by varying the polymerization charge density at different applied potentials.



Figure 2. (A) Top-view SEM image before (upper part) and after PEDOT (lower part) electrodeposition and (B) cross-sectional FIB-SEM image of a PSC, where the PEDOT electrodeposition was carried out at E = 1.0 V with  $Q_{pol} = 5$  mC cm<sup>-2</sup>. (C) Theoretical and actual PEDOT layer thicknesses (determined from cross-sectional SEM images). (D) Raman-spectra of a fully assembled FTO/TiO<sub>2</sub>/MAPbI<sub>3</sub>/PEDOT architecture and a FTO/PEDOT reference material.

des with a thin MAPbI<sub>3</sub> layer were fabricated to monitor the optical changes during electrochemical deposition of the HTM layer, as described in the Supporting Information. The time frame of the experiment and potential-range of the PEDOT electrodeposition (in the absence of bis-EDOT monomer) was established through prolonged immersion of the FTO/TiO<sub>2</sub>/ MAPbI<sub>3</sub> electrode in the solvent and carrying out cyclic voltammetric experiments. As established in our earlier methods and protocol work,<sup>29</sup> 0.1 M Bu<sub>4</sub>NPF<sub>6</sub> in dichloromethane offers the best electrochemical condition as no significant change in the overall shape of the optical absorption of the perovskite film is observed after 10 min of exposure (Figure S1A). As for the electrochemical properties,  $MAPbI_3$ layers were more resistant to oxidation than reduction (Figure S1B). Top-down and cross-sectional SEM images as well as XPS studies confirmed the stability of the FTO/TiO<sub>2</sub>/MAPbI<sub>3</sub> electrodes during both immersion in the electrolyte and oxidative biasing, up to 1.1 V (Figures S2 and S3). However,

EDOT cannot be used as the polymerization precursor, because its polymerization (oxidation) potential would exceed the electrochemical stability of MAPbI<sub>3</sub> layers. To overcome this limitation, we employed bis-EDOT as a precursor (Scheme S1). The use of bis-EDOT, in turn, allowed us to carry out the (oxidative) electropolymerization and produce PEDOT films without degrading the MAPbI<sub>3</sub> layer.<sup>35</sup>

The electropolymerization process initiated by the electrochemical oxidation of bis-EDOT on  $FTO/TiO_2/MAPbI_3$ electrodes was monitored using *in situ* spectroelectrochemical experiments (Figure 1A–C). The gradual growth of PEDOT during potentiodynamic deposition was evident from the change in absorption as well as the increasing (pseudo)capacitive current in the potential range of 0.0–0.6 V. The absorption peak at 450 nm was attributed to EDOT oligomers and the broad absorption in the 500–800 nm region (Figure 1B) was assigned to the polymer product, viz., PEDOT layer. To correlate the polymer formation with the oxidation of bisEDOT, the current density of the first polymerization half cycle was plotted along with the absorbance increase at 700 nm (Figure 1C). A sharp rise in the current at 0.7 V was accompanied by the absorbance increase at 700 nm, thus confirming the polymerization of bis-EDOT.

Although polymerization starts at 0.7 V, prolonged exposure to the electrolyte needs to be avoided. As shown in Figure 1D, adequate polymerization rate was achieved at potentials above 0.9 V. In addition, by varying the electrochemical charge density, the thickness of the formed PEDOT layer can be finetuned, as deduced from the absorbance spectra (Figure 1E,F). The UV-vis absorption features did not indicate any noticeable changes corresponding to perovskite layer absorption, thereby confirming the conservation of original MAPbI<sub>3</sub> architecture during the electropolymerization process.

Characterization of PEDOT Layer. SEM images captured the morphological features of the PEDOT layers on the MAPbI<sub>3</sub> film following the deposition of PEDOT at 1.0 V with  $Q_{pol} = 5 \text{ mC cm}^{-2}$ . The top-view images show that the electropolymerized layer of PEDOT completely covers the MAPbI<sub>3</sub> layer (Figure 2A). The smooth MAPbI<sub>3</sub> surface was not visible anymore, instead a furry polymer coating developed. These images confirmed the homogeneity of the PEDOT layer and that the MAPbI<sub>3</sub> remained intact during the electrodeposition. In order to determine the thickness of the formed PEDOT, cross-sectional FIB-SEM images were recorded (Figure 2B). The measured PEDOT thickness was compared with the value, calculated from the charge density employed during polymerization (Figure 2C). These values fall in the range of the HTM thicknesses (40-300 nm) employed in the case of MAPbI<sub>3</sub> PSCs using PEDOT.<sup>21,22</sup> Ramanspectroscopic studies (Figure 2D) further confirmed the characteristics of an electrochemically deposited PEDOT on top of the MAPbI<sub>3</sub> layer.

Post-treatment of PEDOT Layer. The doping level of the HTL is important for optimization of PSCs. When we evaluated the photovoltaic performance of the MAPbI<sub>3</sub> PSCs employing the electrochemically deposited PEDOT holetransporting layers, without any post-treatment (see Supporting Information for detailed analysis (Figure S4)), all of them exhibited low open circuit voltage  $(V_{OC})$  (Figure 3A) and fill factor (FF). The inability of PEDOT layer to transport the holes efficiently results in increased charge recombination (Figure S4). One way to overcome these issues is to modulate the doping level of PEDOT layer. We employed electrochemical post-treatment approach to alter the doping level (Scheme S2). PEDOT films deposited at 1.0 V, with a  $Q_{pol} =$ 3-10 mC cm<sup>-2</sup> seemed to be optimal to evaluate posttreatment conditions. This reductive post-treatment method, however, had an unintended side-effect, as revealed by crosssectional SEM images (Figure S5A,B). Though the reduction of PEDOT is beneficial for its performance, it destroys some of the MAPbI<sub>3</sub> from the underlying layer. Three different strategies were employed to mitigate this effect: (i) rapid reduction at -0.6 V for 10 s (Figure S6A); (ii) mild reduction at -0.5 V for 60 s (Figure S6B); and (iii) rapid-mild reduction at -0.5 V for 20 s (Figure S6C).

There was an improvement in the  $V_{\rm OC}$  of the devices compared to the untreated PEDOT in all cases (Figure S7), but the  $I_{SC}$  and the FF remained low in most cases (Figure S9A–D). The only exception was the rapid reduction, where the champion cell had a 5.9% efficiency (Figure 3D). Topdown and cross-sectional SEM images recorded for samples



cm²

MA 10

Current density

18

dark scan

- illuminated scan

0.4 0.6

Voltage / V

A 0.8

> voltage / V 0

Open circuit

С 0.8

voltage / V

circuit

Open 0.

0.4

0.2

0

0.6

0.4

0.2

Communication

Figure 3. (A) Effect of PEDOT thickness (polymerization charge density) on the open circuit voltage in a FTO/TiO<sub>2</sub>/MAPbI<sub>3</sub>/ PEDOT PSC for PEDOT layers electrodeposited at E = 1.0 V. (B) Chronoamperometric curves recorded for the PEDOT layers electrodeposited at E = 1.0 V, when a reductive post-treatment at E = -0.6 V was employed. (C) Buildup of the open circuit potential in a FTO/TiO2/MAPbI3/PEDOT SC for the PEDOT layers electrodeposited at E = 1.0 V for  $Q_{pol} = 10$  mC cm<sup>-2</sup>. (D) J - V curve of the champion device containing a PEDOT layer electrodeposited at E = 1.0 V for  $Q_{pol} = 10$  mC cm<sup>-2</sup>, where the postreduction step was at E =-0.6 V for t = 10 s.

200

Time / s

post-treated with the rapid reduction revealed that the degradation of the MAPbI3 layers can be avoided using this strategy (Figure S8).

Transient Absorption Measurements. To probe the hole accepting ability of PEDOT, transient absorption spectroscopic measurements were carried out (Figure 4A).



Figure 4. (A) Time-resolved transient spectra of an FTO/TiO<sub>2</sub>/ MAPbI<sub>3</sub>/PEDOT PSC employing a thin MAPbI<sub>3</sub> layer recorded following 387 nm laser pulse excitation. The PEDOT layer was prepared and post-treated just as the champion device. (B) Bleaching recovery profiles at 760 nm of different FTO/TiO<sub>2</sub>/MAPbI<sub>3</sub>/PEDOT PSCs.

The characteristics of the spectra are in good accordance with MAPbI<sub>3</sub> spectra in the literature.<sup>36</sup> The most prominent feature, the ground state bleach at 760 nm, is caused by charge separation due to band edge transition in MAPbI<sub>3</sub>. Furthermore, there is no additional bleaching signal present at ~500 nm that would arise from  $PbI_2$  in the material. The recovery of the 760 nm bleach follows second-order kinetics (Figure 4B). Fitting the data to a biexponential decay reveals that the average lifetime (see Supporting Information for the calculations and detailed analysis) has the following trend: reduced PEDOT  $(t_{weighed avg} = 1280 \text{ ps}) < \text{as-is PEDOT}$  $(t_{weighed avg} = 1660 \text{ ps}) < \text{no HTM}$   $(t_{weighed avg} = 1750 \text{ ps})$ . The shorter lifetime indicates the transfer of photogenerated holes from  $MAPbI_3$  layer to PEDOT layer. Furthermore, the postsynthetic reduction technique improves the hole accepting properties of the PEDOT film.

## CONCLUSIONS

The electrochemical deposition of PEDOT offers a convenient way to deposit a hole-transport layer on a MAPbI<sub>3</sub> layer for designing n-i-p junction perovskite solar cells. By employing potentiostatically controlled electrodeposition technique, it is possible to obtain controlled thicknesses of HTM layers. An electrochemical postreduction step introduced to control the doping level of the as-deposited PEDOT films is an essential step in achieving better performance of PSCs. Care should be exercised not to destroy the underlying MAPbI<sub>3</sub> layer during the post-treatment process. The champion device showed a power conversion efficiency of 5.9%. The results presented in this study open new opportunities to employ electrochemistry to assemble complex architectures of optically active perovskites.

## ASSOCIATED CONTENT

## **Supporting Information**

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acs.chemma-ter.8b01521.

Detailed synthesis and characterization procedures, electrochemical stability tests, solar cell characterization parameters derived from J-V curves, SEM-FIB images of solar cells, current transients recorded during electrochemical reduction, fitting parameters of transient absorption spectra (PDF)

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## Notes

The authors declare no competing financial interest.

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